## ST(意法) 2SD2012 PDF



# 深圳创唯电子有限公司

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## NPN SILICON POWER TRANSISTOR

- HIGH DC CURRENT GAIN
- LOW SATURATION VOLTAGE
- INSULATED PACKAGE FOR EASY MOUNTING

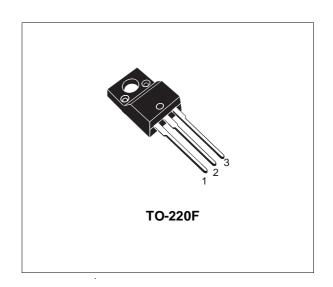
#### **APPLICATIONS**

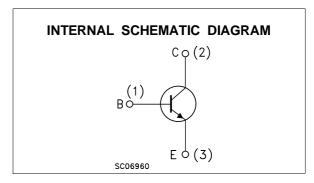
- GENERAL PURPOSE POWER AMPLIFIERS
- GENERAL PURPOSE SWITCHING

#### **DESCRIPTION**

The 2SD2012 is a silicon NPN power transistor housed in TO-220F insulated package.

It is inteded for power linear and switching applications.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)	60	V
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)	7	V
Ic	Collector Current	3	Α
I <sub>CM</sub>	Collector Peak Current (tp < 5 ms)	6	А
Ι <sub>Β</sub>	Base Current	0.5	Α
P <sub>tot</sub>	Total Dissipation at T <sub>c</sub> ≤ 25 °C	25	W
V <sub>isol</sub>	Insulation Withstand Voltage (RMS) from All Three Leads to Exernal Heatsink	1500	V
T <sub>stg</sub>	Storage Temperature	-65 to 150	°C
Tj	Max. Operating Junction Temperature	150	O°

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#### THERMAL DATA

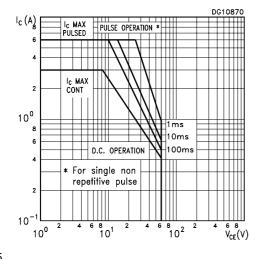
R <sub>thj-case</sub>	Thermal Resistance Junction-case	Max	5	°C/W	1
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## **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25 °C unless otherwise specified)

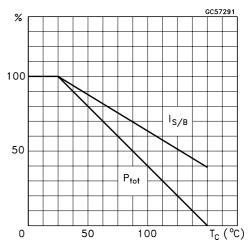
Symbol	Parameter	Test Cond	itions	Min.	Тур.	Max.	Unit
Ісво	Collector Cut-off Current (I <sub>E</sub> = 0)	V <sub>CB</sub> = 60 V				100	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	$V_{EB} = 7 V$				100	μΑ
V <sub>(BR)CEO*</sub>	Collector-Emitter Breakdown Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 50 mA		60			V
V <sub>CE(sat)*</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2 A	$I_B = 0.2 A$		0.4	1	V
$V_{BE}*$	Base-Emitter Voltage	$I_C = 0.5 A$	$V_{CE} = 5 V$		0.75	1	٧
h <sub>FE</sub> *	DC Current Gain	I <sub>C</sub> = 0.5 A I <sub>C</sub> = 2 A	V <sub>CE</sub> = 5 V V <sub>CE</sub> = 5 V	100 20		320	
f <sub>T</sub>	Transition frequency	V <sub>CE</sub> = 5 V	I <sub>C</sub> = 0.5 A		3		MHz
ССВО	Collector-Base Capacitance	V <sub>CB</sub> = 10 V I <sub>E</sub> = 0	f = 1 MHz		35		pF

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle ≤ 2 %

## Safe Operating Area

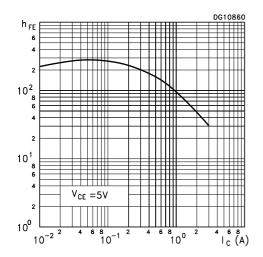


#### **Derating Curve**

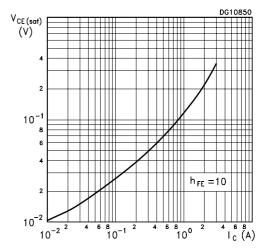


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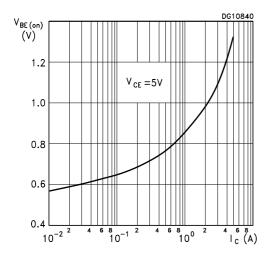
#### DC Current Gain



## Collector Emitter Saturation Voltage

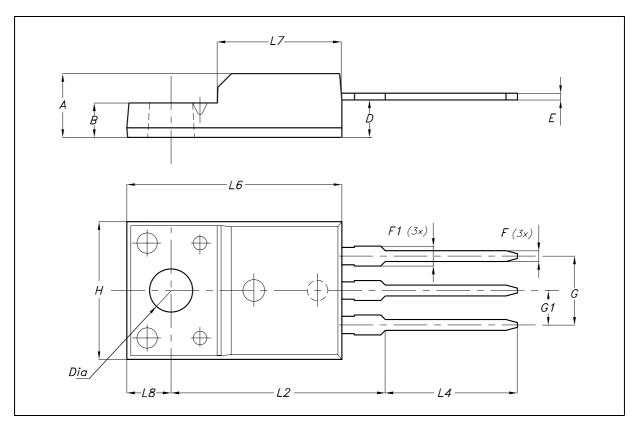


## Base Emitter On Voltage



## **TO-220F MECHANICAL DATA**

DIM.	mm		inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	4.50		4.90	0.177		0.193
В	2.34		2.74	0.092		0.108
D	2.56		2.96	0.101		0.117
Е	0.45	0.50	0.60	0.018	0.020	0.024
F	0.70		0.90	0.028		0.035
F1			1.47			0.058
G		5.08			0.200	
G1	2.34	2.54	2.74	0.092	0.100	0.108
Н	9.96		10.36	0.392		0.408
L2		15.80			0.622	
L4	9.45		10.05	0.372		0.396
L6	15.67		16.07	0.617		0.633
L7	8.99		9.39	0.354		0.370
L8		3.30			0.130	
Dia	3.08		3.28	0.121		0.129



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